Damper-Modulator fast, high-voltage

BYM358X

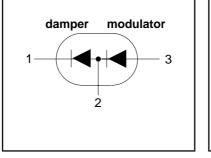
FEATURES

- Low forward volt drop
- Ultra fast switching
- Soft recovery characteristic
 High thermal cycling
- performance
- Isolated mounting tab

SYMBOL

PINNING

3



QUICK REFERENCE DATA

	MODULATOR
V _R =1500 V	V _R =600 V V _F ≤ 1.08 V
$V_F \leq 1.5 V$	$V_F \le 1.08 \text{ V}$
I _{F(peak)} =7 A	$I_{F(peak)} = 7 \text{ A}$ $I_{FSM} \le 70 \text{ A}$ $t_{rr} \le 60 \text{ ns}$
$I_{FSM} \le 66 A$	I _{FSM} ≤ 70 A
t _{rr} ≤ 170 ns	t _{rr} ≤ 60 ns

GENERAL DESCRIPTION

Combined damper and modulator diodes in an isolated plastic envelope for horizontal deflection in PC monitors. The BYM358X contains diodes

with performance characteristics designed specifically for applications from 32kHz to 120kHz

The BYM358X series is supplied in the conventional leaded SOT186A package.

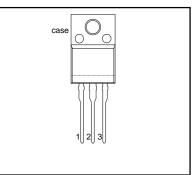
LIMITING VALUES

 $T_i = 25$ °C unless otherwise stated

PIN DESCRIPTION 1 damper cathode

- 2 common anode/cathode
 - modulator anode.

SOT186A



			DAN	IPER	MODU	LATOR	
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	MIN	MAX	UNIT
V _{RSM}	Peak non-repetitive reverse voltage.		-	1500	-	600	V
V_{RRM}	Peak repetitive reverse voltage		-	1500	-	600	V
V_{RWM}	Crest working reverse voltage		-	1300	-	600	V
$\mathbf{I}_{F(peak)}$	Peak forward current	31-70 kHz monitor.	-	7	-	7	A
$\mathbf{I}_{F(RMS)}$	RMS forward current	sinusoidal;a=1.57	-	15.7	-	14.1	A
I _{FSM}	Peak non-repetitive forward current	$\begin{array}{l} t = 10 \text{ ms} \\ t = 8.3 \text{ ms} \\ \text{sinusoidal; with} \\ \text{reapplied} \\ V_{\text{RWM(MAX)}} \end{array}$	-	60 66	-	70 77	A A
T _{stg} T _J	Storage temperature Operating junction temperature		-40 -	150 150	-40 -	150 150	О° О

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ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65% ; clean and dustfree	-	-	2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

			DAN	IPER	MODU	LATOR	
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	with heatsink compound	-	4.8	-	5.5	K/W
R _{th j-a}	Thermal resistance junction to ambient	in free air.	55	-	55	-	K/W

STATIC CHARACTERISTICS OF DAMPER

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F I _R	Forward voltage Reverse current		1.3 1.2 10 300	1.6 1.5 100 500	¥ ∀∀<

STATIC CHARACTERISTICS OF MODULATOR

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX.	UNIT
V _F I _R	Forward voltage Reverse current.		1.2 0.95 1.3 10 100	1.3 1.08 1.45 50 350	V V μΑ μΑ

Product specification

BYM358X

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ELECTRICAL CHARACTERISTICS OF DAMPER

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	I _F = 1 A; V _R ≥ 30 V; -dI _F /dt = 50 A/μs	130	170	ns
Q _s V _{fr}	Reverse recovery charge Peak forward recovery voltage	$I_{\rm F}$ = 6.5 A; dI_{\rm F}/dt = 50 A/\mu s I_{\rm F} = 6.5 A;	0.65 29	0.9 -	μC V

ELECTRICAL CHARACTERISTICS OF MODULATOR

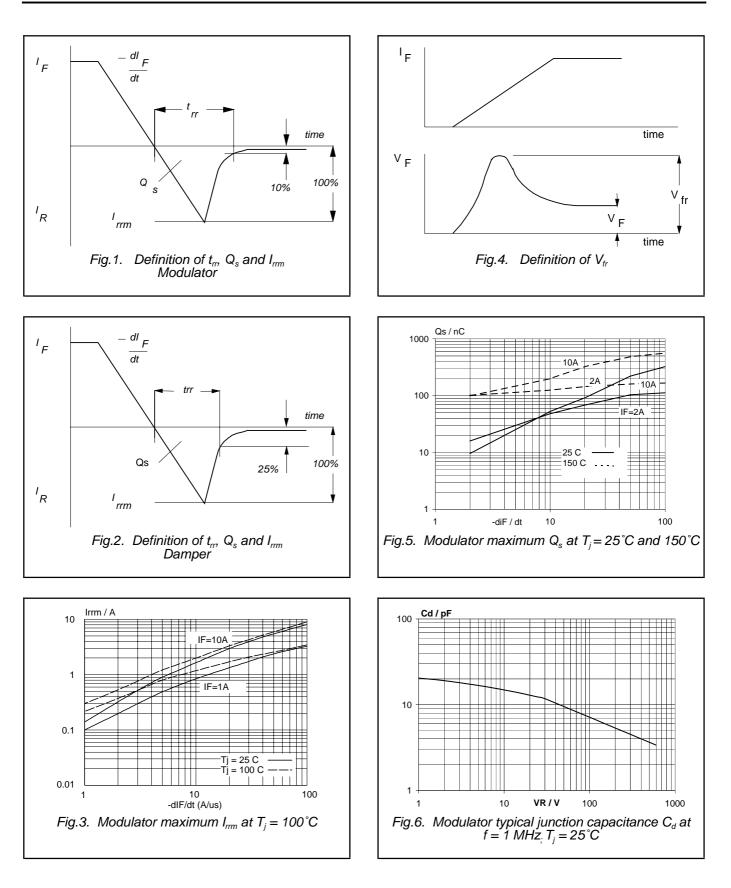
 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
t _{rr}	Reverse recovery time	I _F = 1 A; V _R ≥ 30 V; -dI _F /dt = 100 A/μs	35	60	ns
I _{rrm}	Peak reverse recovery current	$I_F = 10 \text{ A to } V_R \ge 30 \text{ V};$ $dI_F/dt = 50 \text{ A/}\mu\text{s}; T_i = 100^{\circ}\text{C}$	3.0	5.5	A
Q _s V _{fr}	Reverse recovery charge Peak forward recovery voltage	2 A,30 V,20 A/μs I _F = 10 A; dI _F /dt = 10 A/μs	40 5.0	70 -	nC V

Product specification

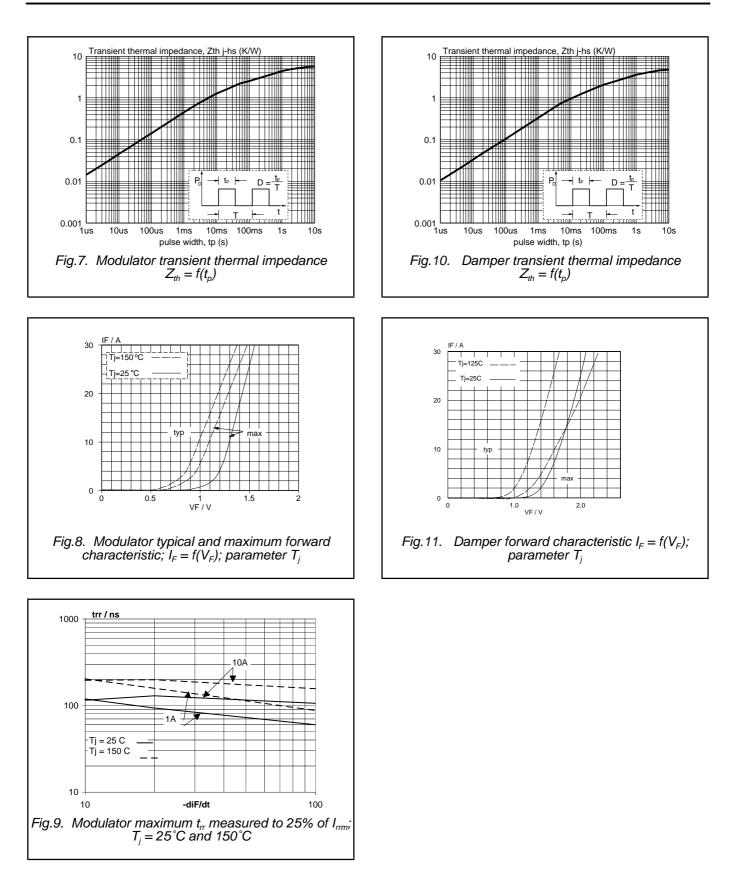
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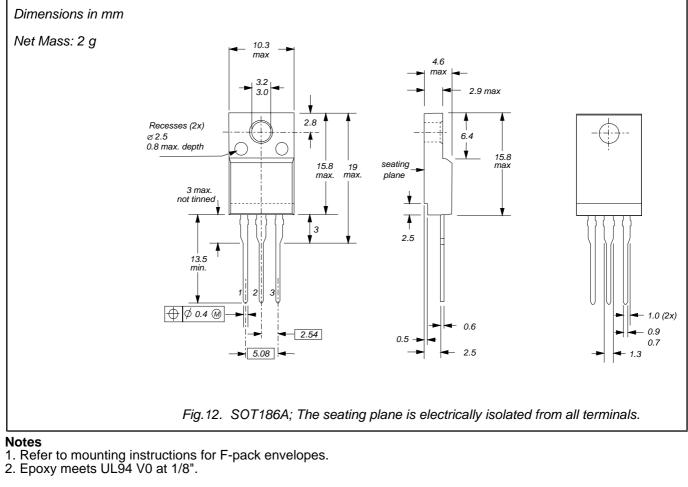
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Damper-Modulator fast, high-voltage

BYM358X

MECHANICAL DATA



Damper-Modulator fast, high-voltage

BYM358X

DEFINITIONS

Data sheet status	Data sheet status					
Objective specification This data sheet contains target or goal specifications for product development.						
Preliminary specification This data sheet contains preliminary data; supplementary data may be published late						
Product specification	This data sheet contains final product specifications.					
Limiting values						
or more of the limiting val operation of the device at	Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information						
Where application information is given, it is advisory and does not form part of the specification.						
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